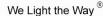
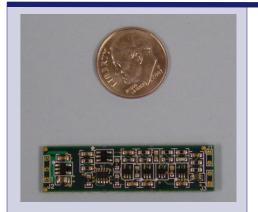


PSI-2011-11 Quad+ Modulator Bias Controller





Features

- » Maintains Bias > ±1° of Quad+
- » Includes Auto-reset
- » Small and Simple to Integrate Into System
- » Factory adjustable dither frequency
- » Customization Available

Applications

- » Optical Modulator Communications Systems
- » RF and Microwave Photonic Transmitters
- » Spectroscopy Systems
- » Optical Test Systems
- » Optical Modulator Component Evaluation
- » Optical Delay Lines

PHOTONIC SYSTEMS INC.

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Description

The PSI-2011-11 mini optical modulator bias controller (MBC) offers comprehensive control of external optical modulators from a single, small form factor circuit board. The PSI-2011-11 provides automatic tracking of Quadbias point as shown in Figure 1. If required, the PSI-2011-11 MBC can be customized by PSI for Quad-, Max or Min operation.

Using a standard dither tone set at 1 KHz, the PSI-2011-11 tracks the operating point to within +/- 1° at 1% dither of V_π when operating at quadrature. The dither tone amplitude is factory set to 1% of customer specified nominal $V\pi$. A high degree of bias point accuracy is maintained over a wide operating temperature range of –20°C to +70°C. Using a common photodetector, the bias point accuracy is easily maintained over a >10dB range of optical power. The PSI-2011-11 can be plugged into a mother-board or connections can be made though discrete wiring to the appropriate input/output connector pins.

Along with this standard configuration, PSI can modify the PSI-2011-11 to meet system requirements . Please contact PSI with you application needs.

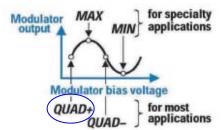
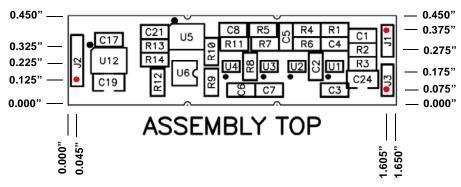


Figure 1- Modulator Transfer

Ordering Information

PSI Part Number	Description
PSI-2011-11	Modulator Bias Controller
	 Please specify nominal modulator DC Vπ at time of order to ensure proper set-up

Mechanical Information



Performance Characteristics

Parameter	Condition	Min	Тур	Max	Units
Modulating Signal	Small Signal				
Modulators Supported	LiNbO ₃				
Modulator/Bias-t Capacitance				0.2	μF
Output DC Bias Port Impedance			100		Ω
Output DC Bias Voltage	Less Than Supply Voltage		1.0		V
Dither Frequency			1.0		KHz
Dither Amplitude	Factory Set per customer modulator	20		200	ppmV
Bias Point Error @ Quad+	150 to 15 µA photocurrent	≥1° @ 1% of Vπ			
DC Supply Voltages		± 8	± 12	± 13	V
DC Operating Current				10	mA

Environmental Characteristics

Parameter	Condition	Min	Тур	Max	Units
Operating Temperature	Within Specifications	0		50	°C
Operating Temperature	Degraded Accuracy (<± 3°)	-20		70	°C
Storage Temperature		-40		85	°C

Pin-out Descriptions

- III out Docomptions				
Designator	Pin	Description		
J1	1	Photodiode Cathode		
	2	Photodiode Anode (Ground)		
J2	1	+12 V _{DC}		
	2	Ground		
	3	-12 V _{DC}		
J3	1	Modulator Bias Output Signal		
	2	Ground		